

# 2A High-Speed MOSFET Drivers

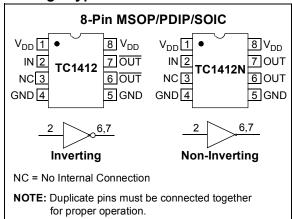
#### **Features**

- Latch-Up Protected: Will Withstand 500 mA Reverse Current
- · Input Will Withstand Negative Inputs Up to 5V
- · ESD Protected: 4 kV
- · High Peak Output Current: 2A
- · Wide Input Supply Voltage Operating Range:
  - 4.5V to 16V
- · High Capacitive Load Drive Capability:
  - 1000 pF in 18 nsec
- · Short Delay Time: 35 nsec Typ.
- · Matched Delay Times
- · Low Supply Current:
  - With Logic '1' Input: 500 μA
- With Logic '0' Input: 100 μA
- Low Output Impedance:  $4\Omega$
- Available in Space-Saving 8-pin MSOP Package
- Pinout Same as TC1410/TC1411/TC1413

#### **Applications**

- · Switch Mode Power Supplies
- · Pulse Transformer Drive
- · Line Drivers
- · Relay Driver

#### **Package Type**

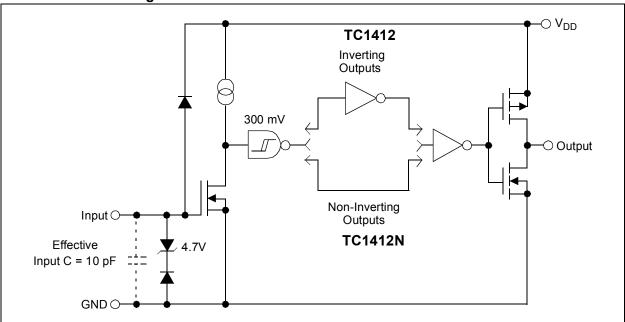


#### **General Description**

The TC1412/TC1412N are 2A CMOS buffers/drivers. They will not latch-up under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of current of either polarity being forced back into their output. All terminals are fully protected against up to 4 kV of electrostatic discharge.

As MOSFET drivers, the TC1412/TC1412N can easily charge a 1000 pF gate capacitance in 18 nsec with matched rise and fall times, and provide low enough impedance in both the ON and the OFF states to ensure the MOSFET's intended state will not be affected, even by large transients. The leading and trailing edge propagation delay times are also matched to allow driving short-duration inputs with greater accuracy.

### **Functional Block Diagram**



# 1.0 ELECTRICAL CHARACTERISTICS

#### **Absolute Maximum Ratings †**

Supply Voltage+20V
Input Voltage $V_{DD}$ + 0.3V to GND – 5.0V
Power Dissipation (T <sub>A</sub> ≤ 70°C)
MSOP340 mW
PDIP730 mW
SOIC470 mW
Storage Temperature Range65°C to +150°C
Maximum Junction Temperature+150°C

<sup>†</sup> Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### PIN FUNCTION TABLE

Symbol	Description					
V <sub>DD</sub>	Supply input, 4.5V to 16V					
INPUT	Control input					
NC	No connection					
GND	Ground					
GND	Ground					
OUTPUT	CMOS push-pull output, common to pin 7					
OUTPUT	CMOS push-pull output, common to pin 6					
V <sub>DD</sub>	Supply input, 4.5V to 16V					

#### DC ELECTRICAL CHARACTERISTICS

**Electrical Specifications:** Unless otherwise noted, over operating temperature range with  $4.5V \le V_{DD} \le 16V$ . Typical values are measured at  $T_A = +25^{\circ}C$ ,  $V_{DD} = 16V$ .

Typical values are measured at T <sub>A</sub> = +25°C, V <sub>DD</sub> = 16V.							
Parameters	Sym	Min	Тур	Max	Units	Conditions	
Input							
Logic '1', High Input Voltage	V <sub>IH</sub>	2.0	_	_	V		
Logic '0', Low Input Voltage	$V_{IL}$	_	_	0.8	V		
Input Current	I <sub>IN</sub>	-1.0	_	1.0	μΑ	$0V \le V_{IN} \le V_{DD}, T_A = +25^{\circ}C$	
		-10	_	10		-40°C ≤ T <sub>A</sub> ≤ +85°C	
Output							
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> – 0.025	_	_	V	DC Test	
Low Output Voltage	V <sub>OL</sub>	_	_	0.025	V	DC Test	
Output Resistance	R <sub>O</sub>	_	4	6	Ω	$V_{DD}$ = 16V, $I_{O}$ = 10 mA, $T_{A}$ = +25°C	
		_	5	7		0°C ≤ T <sub>A</sub> ≤ +70°C	
		_	5	7		-40°C ≤ T <sub>A</sub> ≤ +85°C	
Peak Output Current	I <sub>PK</sub>	_	2.0	_	Α	V <sub>DD</sub> = 16V	
Latch-Up Protection	I <sub>REV</sub>	_	0.5	_	Α	Duty cycle $\leq 2\%$ , t $\leq 300 \mu sec$ ,	
Withstand Reverse Current						V <sub>DD</sub> = 16V	
Switching Time (Note 1)							
Rise Time	t <sub>R</sub>	_	18	26	nsec	$T_A = +25^{\circ}C$	
		_	20	31		0°C ≤ T <sub>A</sub> ≤ +70°C	
		_	22	31		$-40^{\circ}\text{C} \le \text{T}_{A} \le +85^{\circ}\text{C}$ , Figure 4-1	
Fall Time	t <sub>F</sub>	_	18	26	nsec	T <sub>A</sub> = +25°C	
		_	20	31		0°C ≤ T <sub>A</sub> ≤ +70°C	
		_	22	31		-40°C ≤ T <sub>A</sub> ≤ +85°C, <b>Figure 4-1</b>	

Note 1: Switching times ensured by design.

### DC ELECTRICAL CHARACTERISTICS (CONTINUED)

**Electrical Specifications:** Unless otherwise noted, over operating temperature range with  $4.5V \le V_{DD} \le 16V$ . Typical values are measured at  $T_A = +25$ °C,  $V_{DD} = 16V$ .

3.1	71								
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Delay Time	t <sub>D1</sub>	_	35	45	nsec	T <sub>A</sub> = +25°C,			
		_	40	50		0°C ≤ T <sub>A</sub> ≤ +70°C			
		_	40	50		-40°C ≤ T <sub>A</sub> ≤ +85°C, <b>Figure 4-1</b>			
Delay Time	t <sub>D2</sub>	_	35	45	nsec	T <sub>A</sub> = +25°C			
		_	40	50		0°C ≤ T <sub>A</sub> ≤ +70°C			
		_	40	50		-40°C ≤ T <sub>A</sub> ≤ +85°C, <b>Figure 4-1</b>			
Power Supply									
Power Supply Current	I <sub>S</sub>	_	0.5	1.0	mA	V <sub>IN</sub> = 3V, V <sub>DD</sub> = 16V			
		_	0.1	0.15		$V_{IN} = 3V$ , $V_{DD} = 16V$ $V_{IN} = 0V$			

Note 1: Switching times ensured by design.

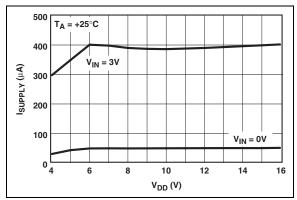
#### **TEMPERATURE CHARACTERISTICS**

<b>Electrical Specifications:</b> Unless otherwise noted, all parameters apply with $4.5V \le V_{DD} \le 18V$ .							
Parameters	Sym	Min	Тур	Max	Units	Conditions	
Temperature Ranges							
Specified Temperature Range (C)	T <sub>A</sub>	0	_	+70	°C		
Specified Temperature Range (E)	T <sub>A</sub>	-40	_	+85	°C		
Maximum Junction Temperature	TJ	_	_	+150	°C		
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C		
Package Thermal Resistances							
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	_	206	_	°C/W		
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	125	_	°C/W		
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	155	_	°C/W		

#### 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

**Note:** Unless otherwise indicated, over operating temperature range with  $4.5V \le V_{DD} \le 16V$ .



**FIGURE 2-1:** Quiescent Supply Current vs. Supply Voltage.

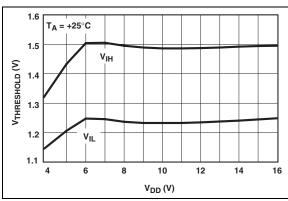
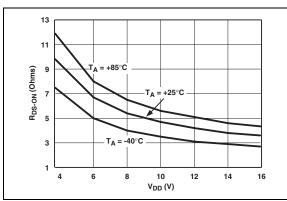
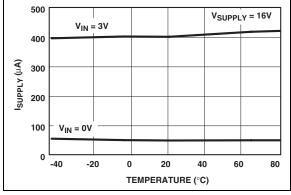


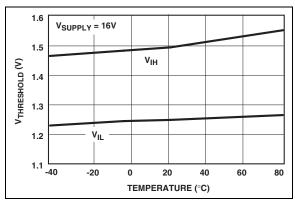
FIGURE 2-2: Input Threshold vs. Supply Voltage.



**FIGURE 2-3:** High-State Output Resistance vs. Supply Voltage.



**FIGURE 2-4:** Quiescent Supply Current vs. Temperature.



**FIGURE 2-5:** Input Threshold vs. Temperature.

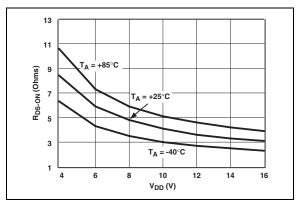


FIGURE 2-6: Low-State Output Resistance vs. Supply Voltage.

**Note:** Unless otherwise indicated, over operating temperature range with  $4.5V \le V_{DD} \le 16V$ .

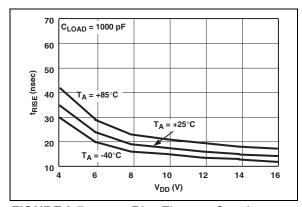


FIGURE 2-7: Voltage.

Rise Time vs. Supply

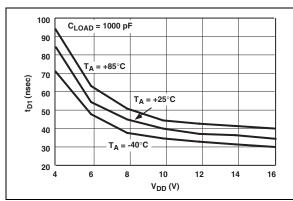
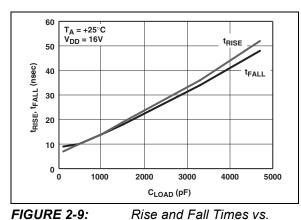


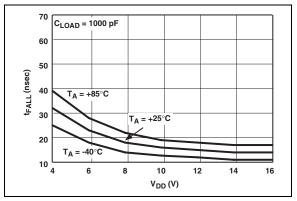
FIGURE 2-8: Supply Voltage.

Propagation Delay vs.



Capacitive Load.

Rise and Fall Times vs.



Voltage.

**FIGURE 2-10:** Fall Time vs. Supply

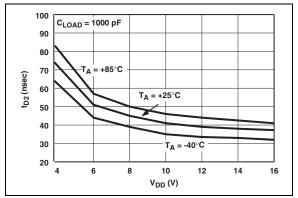
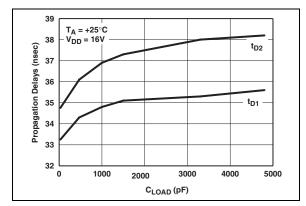


FIGURE 2-11: Supply Voltage.

Propagation Delay vs.



**FIGURE 2-12:** Capacitive Load.

Propagation Delays vs.

#### 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	Symbol	Description
1	$V_{DD}$	Supply input, 4.5V to 16V
2	INPUT	Control input
3	NC	No connection
4	GND	Ground
5	GND	Ground
6	OUTPUT	CMOS push-pull output, common to pin 7
7	OUTPUT	CMOS push-pull output, common to pin 6
8	$V_{DD}$	Supply input, 4.5V to 16V

#### 3.1 Supply Input (V<sub>DD</sub>)

The  $V_{DD}$  input is the bias supply for the MOSFET driver and is rated for 4.5V to 16V with respect to the ground pin. The  $V_{DD}$  input should be bypassed to ground with a local ceramic capacitor. The value of the capacitor should be chosen based on the capacitive load that is being driven. A value of 1.0  $\mu F$  is suggested.

#### 3.2 Control Input (INPUT)

The MOSFET driver input is a high-impedance, TTL/CMOS-compatible input. The input has 300 mV of hysteresis between the high and low thresholds which prevents output glitching even when the rise and fall time of the input signal is very slow.

# 3.3 CMOS Push-Pull Output (OUTPUT)

The MOSFET driver output is a low-impedance, CMOS push-pull style output, capable of driving a capacitive load with 2A peak currents.

#### 3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high peak currents that discharge the load capacitor. The ground pins should be tied into a ground plane or have very short traces to the bias supply source return.

#### 3.5 No Connect (NC)

No internal connection.

#### 4.0 APPLICATION INFORMATION

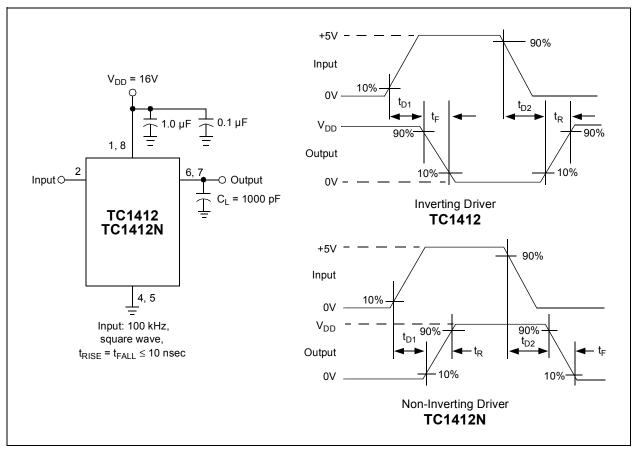
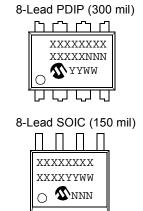
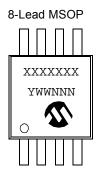


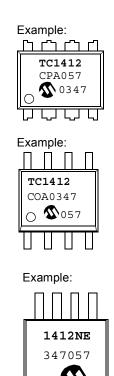
FIGURE 4-1: Switching Time Test Circuit.

#### 5.0 PACKAGING INFORMATION

### 5.1 Package Marking Information







**Legend:** XX...X Customer specific information\* YY Year code (last 2 digits of calendar year)

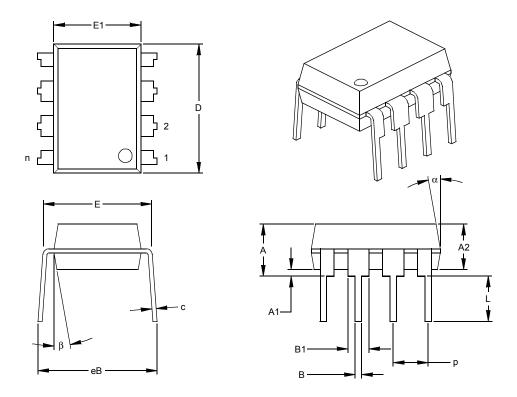
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

**Note**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

## 8-Lead Plastic Dual In-line (PA) - 300 mil (PDIP)



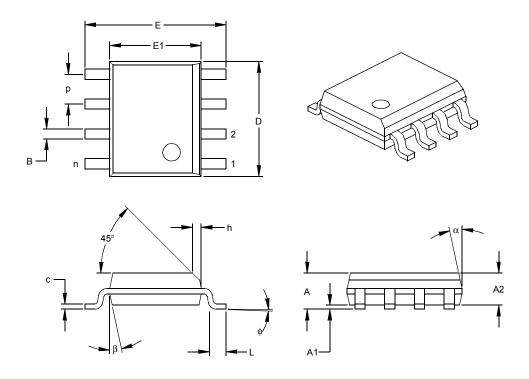
	Units		INCHES*		N	IILLIMETERS	3
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

<sup>\*</sup> Controlling Parameter § Significant Characteristic

### 8-Lead Plastic Small Outline (OA) - Narrow, 150 mil (SOIC)



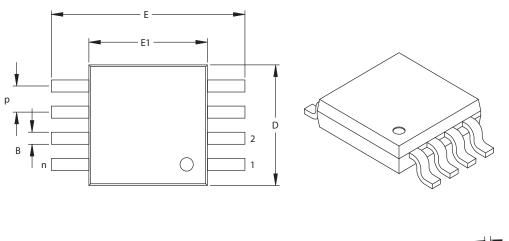
	Units		INCHES*		N	IILLIMETERS	3
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

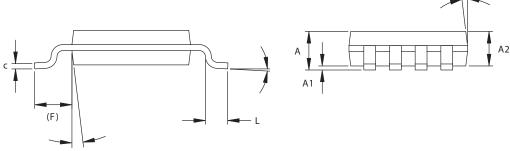
<sup>\*</sup> Controlling Parameter § Significant Characteristic

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

## 8-Lead Plastic Micro Small Outline Package (UA) (MSOP)





	INCHES			М	ILLIMETERS	*	
Dimension Lim	nits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026 BSC			0.65 BSC	
Overall Height	Α	-	1	.043	ı	-	1.10
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95
Standoff	A1	.000	1	.006	0.00	-	0.15
Overall Width	E		.193 BSC		4.90 BSC		
Molded Package Width	E 1		.118 BSC		3.00 BSC		
Overall Length	D		.118 BSC		3.00 BSC		
Foot Length	L	.016	.024	.031	0.40	0.60	0.80
Footprint (Reference)	F		.037 REF			0.95 REF	
Foot Angle		0°	-	8°	0°	-	8°
Lead Thickness	С	.003	.006	.009	0.08	-	0.23
Lead Width	В	.009	.012	.016	0.22	-	0.40
Mold Draft Angle Top		5°	-	15°	5°	-	15°
Mold Draft Angle Bottom		5°	-	15°	5°	-	15°

\*Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

#### PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>X</u> / <u>XX</u>	Examples:
Device:	Temperature Package Range  TC1412: 2 A Single MOSFET Driver, Inverting TC1412N: 2 A Single MOSFET Driver, Non-Inverting	<ul> <li>a) TC1412COA: 2A Single MOSFET driver, SOIC package, 0°C to +70°C.</li> <li>b) TC1412CPA: 2A Single MOSFET driver, PDIP package, 0°C to +70°C.</li> <li>c) TC1412EUA713: Tape and Reel, 2A Single MOSFET driver, MSOP package, -40°C to +85°C.</li> </ul>
Temperature Range: Package:	C = 0°C to +70°C E = -40°C to +85°C  OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel)  UA = Plastic Micro Small Outline (MSOP), 8-lead * UA713 = Plastic Micro Small Outline (MSOP), 8-lead * (Tape and Reel)  PA = Plastic DIP (300 mil Body), 8-lead  * MSOP package is only available in E-Temp.	<ul> <li>a) TC1412NCPA: 2A Single MOSFET driver, PDIP package, 0°C to +70°C.</li> <li>b) TC1412NEPA: 2A Single MOSFET driver, PDIP package, -40°C to +85°C.</li> <li>c) TC1412NEUA: 2A Single MOSFET driver, MSOP package, -40°C to +85°C.</li> </ul>

### Sales and Support

#### **Data Sheets**

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

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- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
- 3. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

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4570 Westgrove Drive, Suite 160 Addison, TX 75001 Tel: 972-818-7423 Fax: 972-818-2924

#### **Detroit**

Tri-Atria Office Building 32255 Northwestern Highway, Suite 190 Farmington Hills, MI 48334 Tel: 248-538-2250 Fax: 248-538-2260

#### Kokomo

2767 S. Albright Road Kokomo, IN 46902

Tel: 765-864-8360 Fax: 765-864-8387

#### Los Angeles

18201 Von Karman, Suite 1090 Irvine, CA 92612 Tel: 949-263-1888 Fax: 949-263-1338

#### **Phoenix**

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7966 Fax: 480-792-4338

#### San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

#### Toronto

6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

#### ASIA/PACIFIC

#### Australia

Microchip Technology Australia Pty Ltd Marketing Support Division Suite 22, 41 Rawson Street Epping 2121, NSW Australia

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

#### China - Beijing

Microchip Technology Consulting (Shanghai) Co., Ltd., Beijing Liaison Office Unit 915 Bei Hai Wan Tai Bldg.

No. 6 Chaoyangmen Beidajie Beijing, 100027, No. China

Tel: 86-10-85282100 Fax: 86-10-85282104

#### China - Chengdu

Microchip Technology Consulting (Shanghai) Co., Ltd., Chengdu Liaison Office Rm. 2401-2402, 24th Floor, Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China

# Tel: 86-28-86766200 Fax: 86-28-86766599 **China - Fuzhou**

Microchip Technology Consulting (Shanghai) Co., Ltd., Fuzhou Liaison Office Unit 28F, World Trade Plaza No. 71 Wusi Road

Fuzhou 350001, China

Tel: 86-591-7503506 Fax: 86-591-7503521

#### China - Hong Kong SAR

Microchip Technology Hongkong Ltd. Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

#### China - Shanghai

Microchip Technology Consulting (Shanghai) Co., Ltd.

Room 701, Bldg. B Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051

Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

#### China - Shenzhen

Microchip Technology Consulting (Shanghai) Co., Ltd., Shenzhen Liaison Office Rm. 1812, 18/F, Building A, United Plaza No. 5022 Binhe Road, Futian District Shenzhen 518033, China Tel: 86-755-82901380 Fax: 86-755-82966626

#### China - Qingdao

Rm. B505A, Fullhope Plaza, No. 12 Hong Kong Central Rd. Qingdao 266071, China Tel: 86-532-5027355 Fax: 86-532-5027205

#### India

Microchip Technology Inc.
India Liaison Office
Marketing Support Division
Divyasree Chambers
1 Floor, Wing A (A3/A4)
No. 11, O'Shaugnessey Road
Bangalore, 560 025, India
Tel: 91-80-2290061 Fax: 91-80-2290062

#### Japan

Microchip Technology Japan K.K. Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471-6166 Fax: 81-45-471-6122

#### Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882

Tel: 82-2-554-7200 Fax: 82-2-558-5934

#### Singapore

Microchip Technology Singapore Pte Ltd. 200 Middle Road #07-02 Prime Centre Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850

#### Taiwan

Microchip Technology (Barbados) Inc., Taiwan Branch 11F-3, No. 207 Tung Hua North Road Taipei, 105, Taiwan Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

#### **EUROPE**

#### Austria

Microchip Technology Austria GmbH Durisolstrasse 2 A-4600 Wels Austria

Tel: 43-7242-2244-399 Fax: 43-7242-2244-393

#### Denmark

Microchip Technology Nordic ApS Regus Business Centre Lautrup hoj 1-3 Ballerup DK-2750 Denmark Tel: 45-4420-9895 Fax: 45-4420-9910

#### France

Microchip Technology SARL
Parc d'Activite du Moulin de Massy
43 Rue du Saule Trapu
Batiment A - ler Etage
91300 Massy, France
Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

#### Germany

Microchip Technology GmbH Steinheilstrasse 10 D-85737 Ismaning, Germany Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

#### Italy

Microchip Technology SRL Via Quasimodo, 12 20025 Legnano (MI) Milan, Italy

Tel: 39-0331-742611 Fax: 39-0331-466781

#### **United Kingdom**

Microchip Ltd.
505 Eskdale Road
Winnersh Triangle
Wokingham
Berkshire, England RG41 5TU
Tel: 44-118-921-5869 Fax: 44-118-921-5820

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